Product data sheet

1. Product profile

1.1 General description

Planar PIN diode in a SOD882T leadless ultra small plastic SMD package.

1.2 Features

- High voltage, current controlled
- RF resistor for RF attenuators and switches
- Low diode capacitance
- Low diode forward resistance
- Very low series inductance
- For applications up to 3 GHz

1.3 Applications

RF attenuators and switches

2. Pinning information

Table 1. Discrete pinning

Pin	Description	Si	mplified outline	Symbol
1	cathode	<u>[1]</u>		
2	anode		Transparent top view	sym006

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 2. Ordering information

Type number	Package		
	Name	Description	Version
BAP1321LX	-	leadless ultra small plastic package; 2 terminals; body 1 \times 0.6 \times 0.4 mm	SOD882T



4. Marking

Table 3. Marking

Type number	Marking code
BAP1321LX	LH

5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{R}	reverse voltage		-	60	V
I _F	forward current		-	100	mA
P _{tot}	total power dissipation	$T_{sp} = 90 ^{\circ}C$	-	130	mW
T_{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point		74	K/W

7. Characteristics

Table 6. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage	$I_F = 50 \text{ mA}$	-	0.95	1.1	V
I _R	reverse current	V _R = 60 V	-	-	100	nA
C_d	diode capacitance	see Figure 1; f = 1 MHz;				
		$V_R = 0 V$	-	0.32	-	pF
		$V_R = 1 V$	-	0.27	0.38	pF
		V _R = 20 V	-	0.21	0.28	pF
r _D diode forward resistance	see Figure 2; f = 100 MHz;					
		$I_F = 0.5 \text{ mA}$	-	3.3	5.0	Ω
		I _F = 1 mA	-	2.4	3.6	Ω
		I _F = 10 mA	-	1.2	1.8	Ω
		I _F = 100 mA	-	0.9	1.3	Ω
ISL	isolation	see Figure 3; V _R = 0 V;				
		f = 900 MHz	-	17	-	dB
		f = 1800 MHz	-	12	-	dB
		f = 2450 MHz	-	10	-	dB
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Table 6. Characteristics ... continued $T_{amb} = 25 \,^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
L _{ins} insertion loss	insertion loss	see Figure 4; $I_F = 0.5 \text{ mA}$;				
		f = 900 MHz	-	0.25	-	dB
		f = 1800 MHz	-	0.26	-	dB
		f = 2450 MHz	-	0.27	-	dB
L _{ins}	insertion loss	see Figure 4; I _F = 1 mA;				
		f = 900 MHz	-	0.19	-	dB
		f = 1800 MHz	-	0.20	-	dB
		f = 2450 MHz	-	0.21	-	dB
L _{ins} insertion loss	insertion loss	see Figure 4; I _F = 10 mA;				
		f = 900 MHz	-	0.11	-	dB
		f = 1800 MHz	-	0.13	-	dB
	f = 2450 MHz	-	0.14	-	dB	
L _{ins}	insertion loss	see Figure 4; I _F = 100 mA;				
		f = 900 MHz	-	0.09	-	dB
		f = 1800 MHz	-	0.11	-	dB
		f = 2450 MHz	-	0.12	-	dB
τ∟	charge carrier life time	when switched from I $_{F}$ = 10 mA to I $_{R}$ = 6 mA; R $_{L}$ = 100 $\Omega;$ measured at I $_{R}$ = 3 mA	-	0.48	-	μs
L _S	series inductance	I _F = 100 mA; f = 100 MHz	-	0.4	-	nΗ

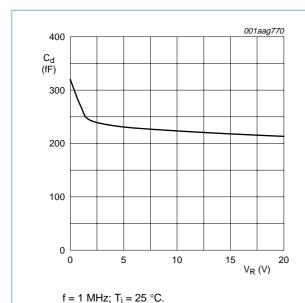


Fig 1. Diode capacitance as a function of reverse voltage; typical values

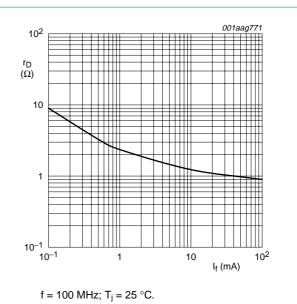
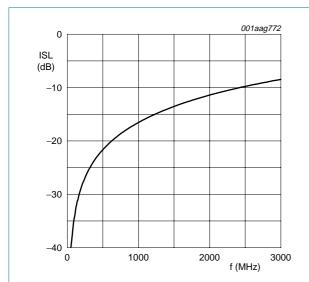
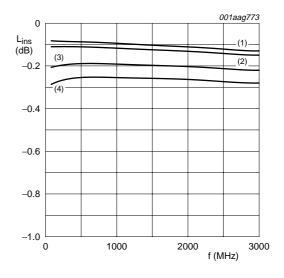


Fig 2. Forward resistance as a function of forward current; typical values



 $T_{amb} = 25 \, ^{\circ}C$

Diode zero biased and inserted in series with a 50 Ω stripline circuit



 $T_{amb} = 25 \, ^{\circ}C$

- (1) $I_F = 100 \text{ mA}$
- (2) $I_F = 10 \text{ mA}$
- (3) $I_F = 1 \text{ mA}$
- (4) $I_F = 0.5 \text{ mA}$

Diode inserted in series with a 50 Ω stripline circuit and biased via the analyzer Tee network

4 of 8

Fig 4. Insertion loss of the diode as a function of frequency; typical values

Fig 3. Isolation of the diode as a function of frequency; typical values

5 of 8

Package outline

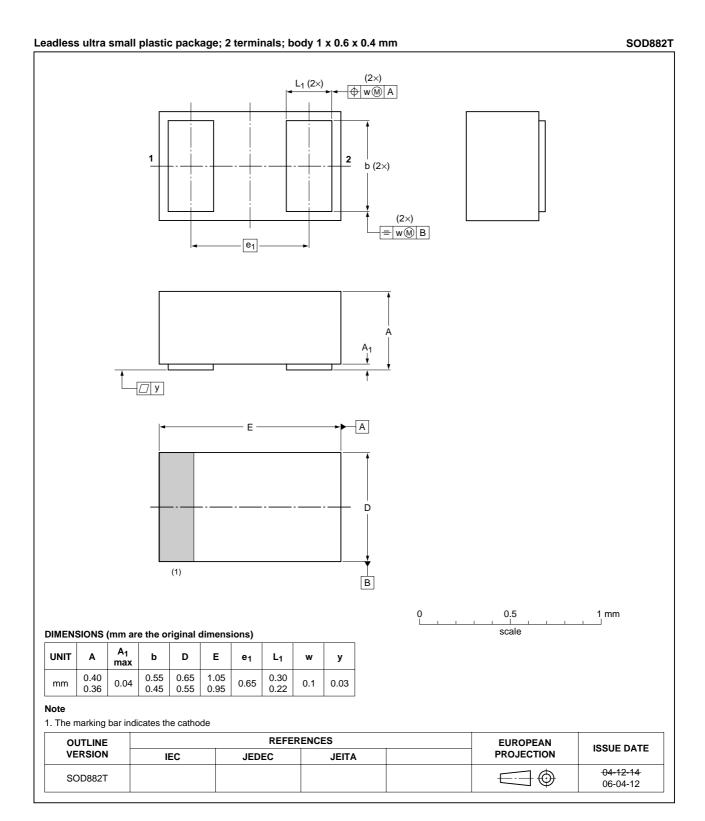


Fig 5. Package outline SOD882T

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9. Abbreviations

Table 7. Abbreviations

Acronym	Description
PIN	P-type, Intrinsic, N-type
SMD	Surface Mounted Device
RF	Radio Frequency

10. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP1321LX_1	20070730	Product data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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13. Contents

Product profile
General description
Features
Applications
Pinning information 1
Ordering information 1
Marking 2
Limiting values
Thermal characteristics
Characteristics
Package outline 5
Abbreviations 6
Revision history 6
Legal information 7
Data sheet status
Definitions
Disclaimers
Trademarks 7
Contact information 7
Contents

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